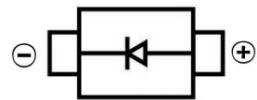


SMB General Purpose Rectifier Diode 通用整流二极管**■Features 特点**

Glass passivated junction 玻璃钝化结
 Low reverse leakage current 低反向漏电流
 Low forward voltage drop 低正向压降
 High current capability 高电流能力
 Surface mount device 表面贴装器件
 Case 封装:SMB(DO-214AA)

**■Maximum Rating 最大额定值**

(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	S3A	S3B	S3D	S3G	S3J	S3K	S3M	Unit 单位
Peak Reverse Voltage 反向峰值电压	V _{RRM}	50	100	200	400	600	800	1000	V
DC Reverse Voltage 直流反向电压	V _R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage RMS 反向电压	V _{R(RMS)}	35	70	140	280	420	560	700	V
Forward Rectified Current 正向整流电流	I _F	3						A	
Peak Surge Current 峰值浪涌电流	I _{FSM}	100						A	
Thermal Resistance J-A 结到环境热阻	R _{θJA}	50						°C/W	
Junction and Storage Temperature 结温和储藏温度	T _J , T _{stg}	150°C,-55to+150°C							

■Electrical Characteristics 电特性

(TA=25°C unless otherwise noted 如无特殊说明, 温度为 25°C)

Characteristic 特性参数	Symbol 符号	Min 最小值	Typ 典型值	Max 最大值	Unit 单位	Condition 条件
Forward Voltage 正向电压	V _F		1.0	1.1	V	I _F =3A
Reverse Current 反向电流	I _R			10	uA	V _R =V _{RRM}
Diode Capacitance 二极管电容	C _D		30		pF	V _R =4V,f=1MHz

■Typical Characteristic Curve 典型特性曲线

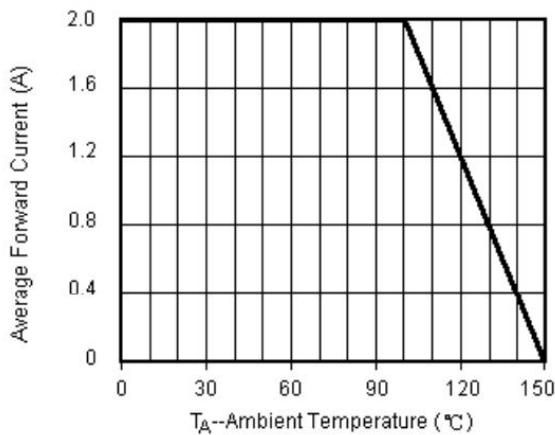


Figure 1: Forward Current Derating Curve

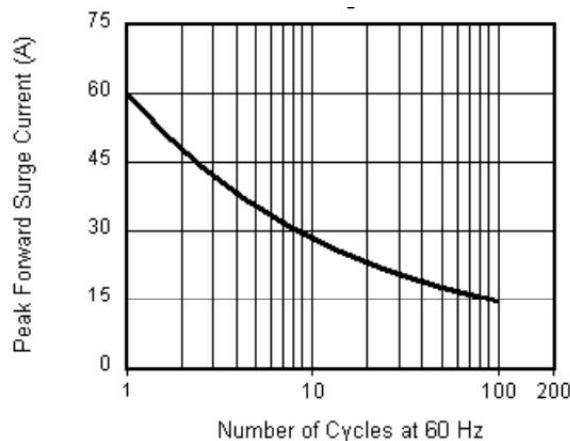


Figure 2: Peak Forward Surge Current

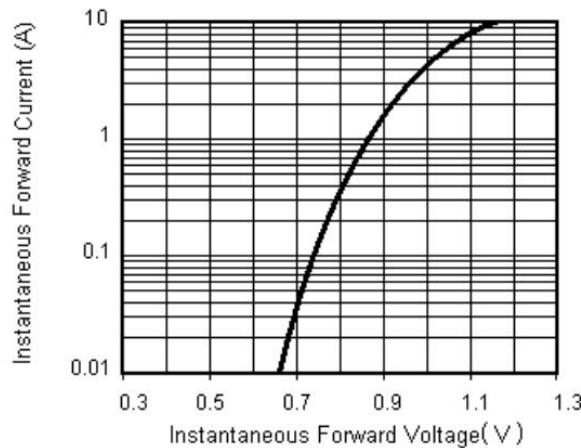


Figure 3: Instantaneous Forward Characteristics

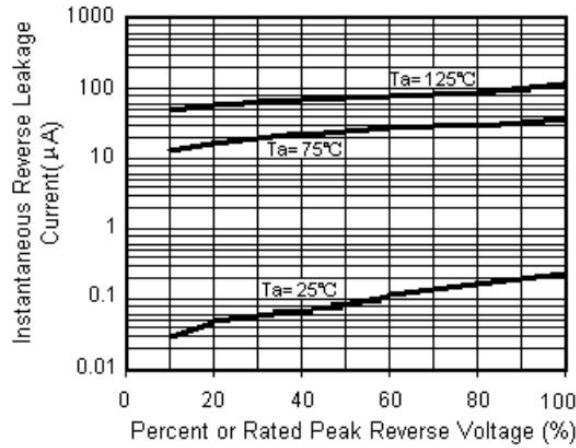


Figure 4: Reverse Leakage Characteristics

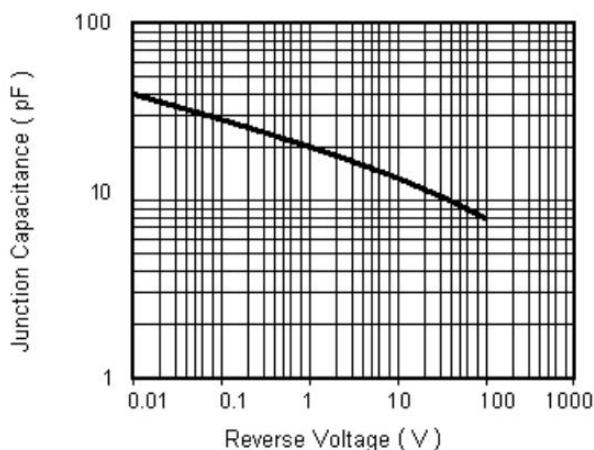


Figure 5: Junction Capacitance

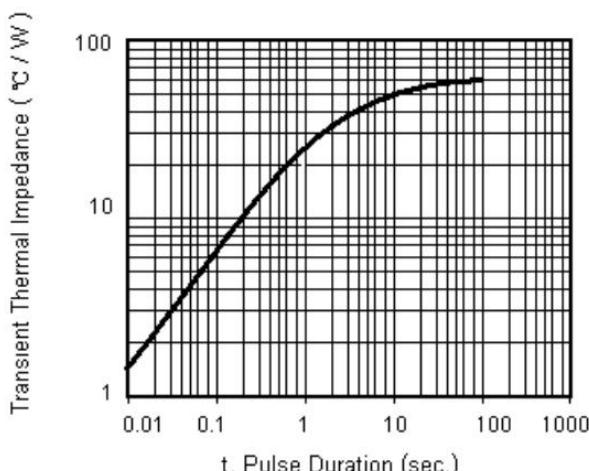
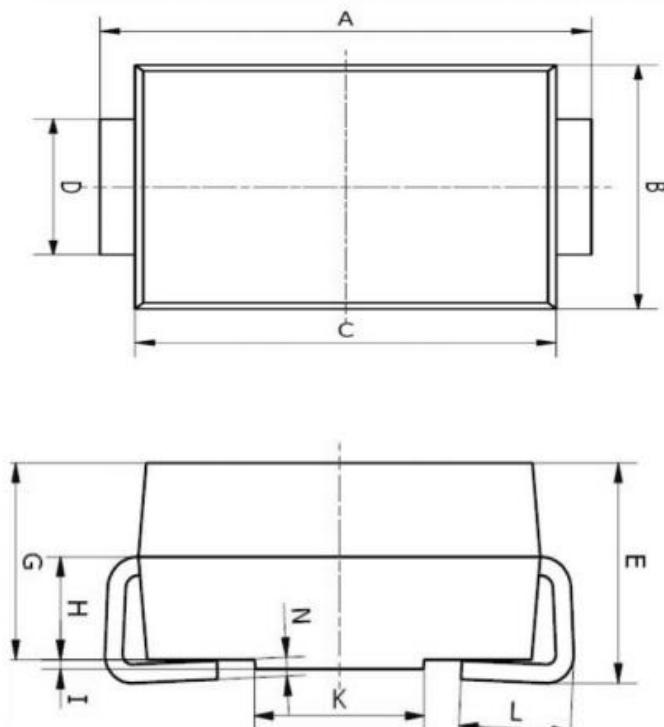


Figure 6: Transient Thermal Impedance

■ Dimension 外形封装尺寸



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	5.00	5.45	0.197	0.215
B	3.20	4.00	0.126	0.157
C	4.30	4.70	0.169	0.185
D	1.80	2.20	0.071	0.087
E	2.20	2.50	0.087	0.098
G	1.90	2.30	0.075	0.090
H	0.95	1.25	0.037	0.049
I	0.05	0.15	0.002	0.006
K	1.70	2.10	0.067	0.083
L	0.90	1.60	0.035	0.063
N	0.10	0.30	0.004	0.012